© Semiconductor Components Industries, LLC, 2016 July, 2016 – Rev. 7

1

Publication Order Number: NTST20100CT/D

3

CASE 221AH

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

NTST20100CTG, NTSB20100CT-1G, NTSJ20100CTG, NTSB20100CTG

Trench-based Dual Schottky Rectifier, Very Low Forward Voltage, 20A, 100V

Features

- Fine Lithography Trench–based Schottky Technology for Very Low Forward Voltage and Low Leakage
- Fast Switching with Exceptional Temperature Stability
- Low Power Loss and Lower Operating Temperature
- Higher Efficiency for Achieving Regulatory Compliance
- Low Thermal Resistance
- High Surge Capability
- These are Pb–Free Devices

Typical Applications

- Switching Power Supplies including Notebook / Netbook Adapters, ATX and Flat Panel Display
- High Frequency and DC–DC Converters
- Freewheeling and OR-ing diodes
- Reverse Battery Protection
- Instrumentation

Mechanical Characteristics

- Case: Epoxy, Molded
- Epoxy Meets Flammability Rating UL 94-0 @ 0.125 in
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Maximum for 10 sec



ON Semiconductor®

www.onsemi.com

PIN CONNECTIONS

O 2, 4

CASE 418B

10

TO-220AB CASE 221A STYLE 6 TO-220FP TO-220FP TO-220FP TO-220FP TO-220FP TO-220FP TO-220FP TO-220FP TO-220AB CASE 221A TO-220AB CASE 221A TO-220AB TO-200AB T

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	100	V
Average Rectified Forward Current (Rated V_R , $T_C = 130^{\circ}C$)	Per device Per diode	I _{F(AV)}	20 10	A
Peak Repetitive Forward Current (Rated V_R , Square Wave, 20 kHz, T_C = 125°C)	Per device Per diode	I _{FRM}	40 20	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		I _{FSM}	150	A
Operating Junction Temperature		TJ	-40 to +150	°C
Storage Temperature		T _{stg}	-40 to +150	°C
Voltage Rate of Change (Rated V _R)		dv/dt	10,000	V/μs

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

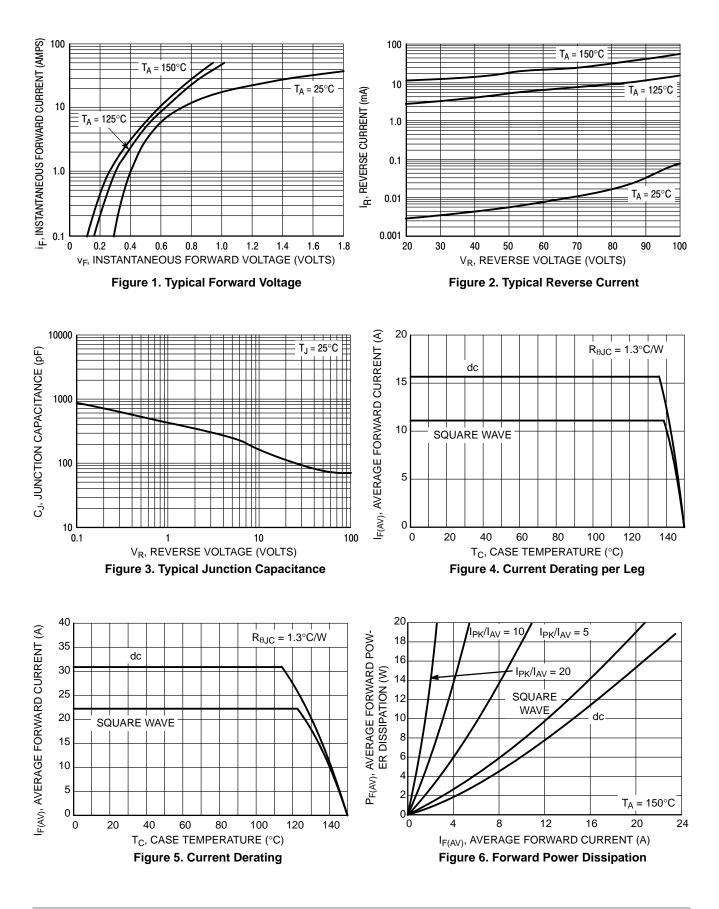
Rating	Symbol	NTST20100CTG, NTSB20100CT-1G	NTSB20100CTG	NTSJ20100CTG	Unit
Maximum Thermal Resistance per Diode Junction-to-Case Junction-to-Ambient	$R_{ heta JC} \ R_{ heta JA}$	2.5 70	1.5 46.9	4.49 105	°C/W °C/W

ELECTRICAL CHARACTERISTICS (Per Leg unless otherwise noted)

Rating	Symbol	Тур	Max	Unit
Maximum Instantaneous Forward Voltage (Note 1)	۷ _F			V
$(I_F = 5 \text{ A}, T_J = 25^{\circ}\text{C})$		0.55	_	
$(I_F = 10 \text{ A}, T_J = 25^{\circ}\text{C})$		0.65	0.83	
$(I_F = 5 \text{ A}, T_J = 125^{\circ}\text{C})$ $(I_F = 10 \text{ A}, T_J = 125^{\circ}\text{C})$		0.50 0.58	_ 0.68	
Maximum Instantaneous Reverse Current (Note 1)	I _R			
$(V_R = 70 \text{ V}, \text{ T}_J = 25^{\circ}\text{C})$		17	-	μΑ
(V _R = 70 V, T _J = 125°C)		5.3	-	mA
(Rated dc Voltage, $T_J = 25^{\circ}C$) (Rated dc Voltage, $T_J = 125^{\circ}C$)		_ 12	800 25	μA mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle $\leq 2.0\%$



TYPICAL CHARACTERISITICS

TYPICAL CHARACTERISITICS

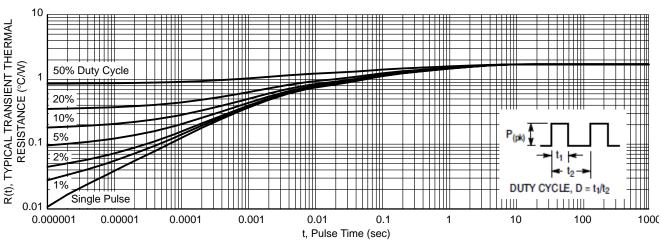
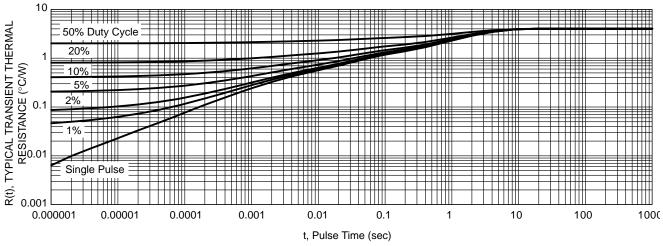
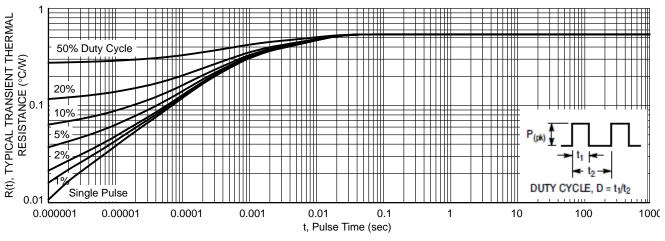


Figure 7. Typical Transient Thermal Response, Junction-to-Case for NTST20100CT and NTSB20100CT-1G









ORDERING INFORMATION

Device	Package	Shipping
NTST20100CTG	TO-220AB (Pb-Free)	50 Units / Rail
NTSB20100CT-1G	l ² PAK (Pb–Free)	50 Units / Rail
NTSJ20100CTG	TO-220FP 50 Units / Rail (Halide-Free)	
NTSB20100CTG	D ² PAK (Pb–Free)	50 Units / Rail
NTSB20100CTT4G	D ² PAK (Pb–Free)	800 / Tape & Reel

AYWW AYWW TS20100CG AYWW AYWW TS20100CG TS2100Cx TS20100CG AKA AKA AKA AKA 1 11 11 $\overline{1}$ I²PAK D²PAK TO-220AB TO-220FP

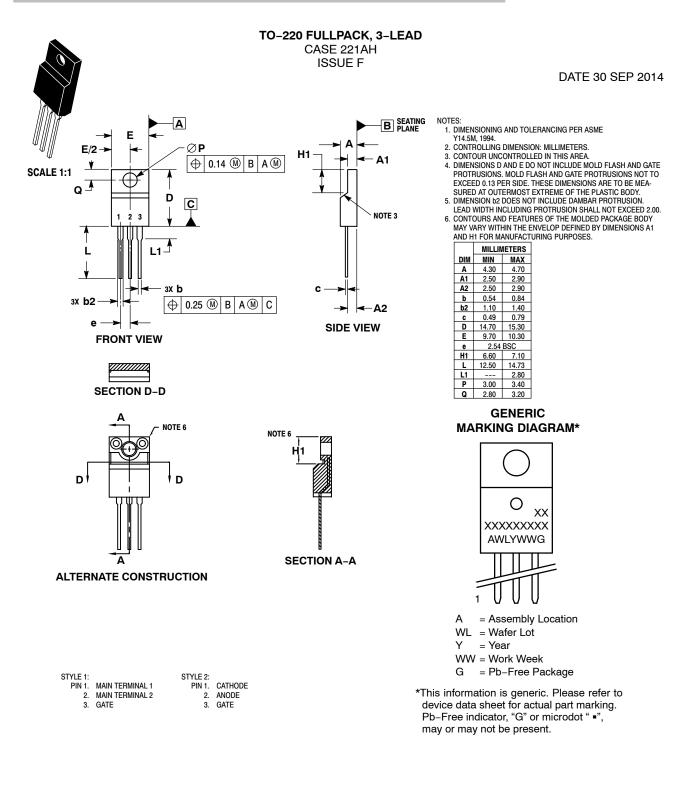
MARKING DIAGRAMS

A = Assembly Location	А	= Assembly Location
-----------------------	---	---------------------

WW = Work Week

- AKA = Polarity Designator
- x = G or H
- G = Pb-Free Package
- H = Halide–Free Package

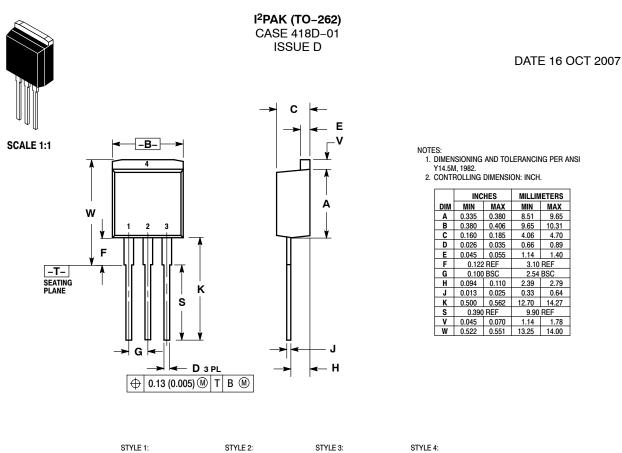




DOCUMENT NUMBER:	MBER: 98AON52577E Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION: TO-220 FULLPACK, 3-LEAD PAGE 1 OF 1						
ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically						

rights of others.



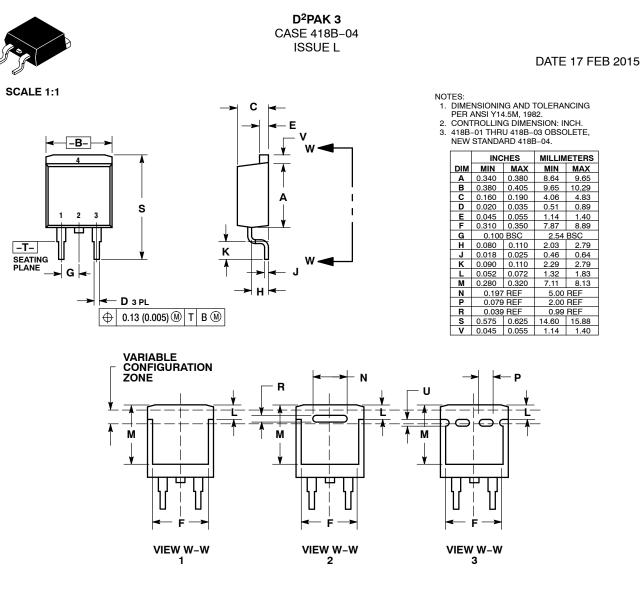


STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:	
PIN 1.	BASE	PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	GATE
2.	COLLECTOR	2.	DRAIN	2.	CATHODE	2.	COLLECTOR
3.	EMITTER	3.	SOURCE	3.	ANODE	3.	EMITTER
4.	COLLECTOR	4.	DRAIN	4.	CATHODE	4.	COLLECTOR

DOCUMENT NUMBER:	98ASB16716C Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	I ² PAK (TO–262)		PAGE 1 OF 1	
ON Semiconductor and (R) are trac	lemarks of Semiconductor Components Indu	stries. LLC dba ON Semiconductor or its subsidiaries in the United States	and/or other countries.	

ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.





STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. GATE	PIN 1. CATHODE	PIN 1. NO CONNECT
2. COLLECTOR	2. DRAIN	2. CATHODE	2. COLLECTOR	2. ANODE	2. CATHODE
3. EMITTER	SOURCE	3. ANODE	3. EMITTER	3. CATHODE	3. ANODE
4. COLLECTOR	4. DRAIN	4. CATHODE	4. COLLECTOR	4. ANODE	4. CATHODE

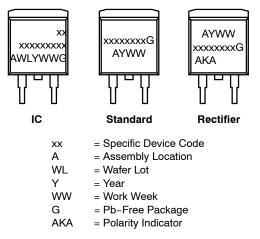
MARKING INFORMATION AND FOOTPRINT ON PAGE 2

DOCUMENT NUMBER:	CUMENT NUMBER: 98ASB42761B Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.						
DESCRIPTION: D ² PAK 3 PAGE 1 OF 2							
ON Semiconductor reserves the righ the suitability of its products for any p	ON Semiconductor and ()) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.						

D²PAK 3 CASE 418B-04 ISSUE L

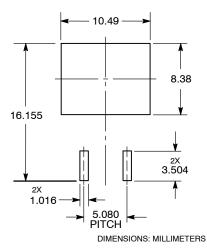
DATE 17 FEB 2015

GENERIC MARKING DIAGRAM*



*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98ASB42761B Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.					
DESCRIPTION: D ² PAK 3 PAGE 2 OF 2						
ON Semiconductor reserves the right the suitability of its products for any pa	to make changes without further notice to an articular purpose, nor does ON Semiconducto	stries, LLC dba ON Semiconductor or its subsidiaries in the United States y products herein. ON Semiconductor makes no warranty, representation r assume any liability arising out of the application or use of any product or cidental damages. ON Semiconductor does not convey any license under	or guarantee regarding circuit, and specifically			

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales